NSN 5961-00-009-2874

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Diode Semiconductor Device - Page 1 of 1



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| View Online at https://aerobasegroup.com/nsn/5961-00-009-2874 |
| Inclosure Material: |
| Glass |
| Overall Length: |
| Between 0.130 inches and 0.300 inches |
| Terminal Length: |
| Between 1.000 inches and 1.500 inches |
| Overall Diameter: |
| Between 0.092 inches and 0.130 inches |
| Mounting Method: |
| Terminal |
| Features Provided: |
| Hermetically sealed case |
| Semiconductor Material: |
| Silicon |
| Voltage Rating In Volts Per Characteristic: |
| 125.0 working peak reverse voltage |
| Current Rating Per Characteristic: |
| 500.00 milliamperes peak forward surge current |
| Maximum Operating Tempurature Per Measurement Point: |
| 175.0 degrees celsius ambient air |
| Test Data Document: |
| 81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification |
| format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain |
| environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). |
| Terminal Type And Quantity: |
| 2 uninsulated wire lead |
| Specification Data: |
| 81349-mil-s-19500/241 government specification |
| Shelf Life: |
| N/a |
| Unit Of Measure: |
| |
| Demilitarization: |
| No |
| Fiig: |